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NO₂ and SO₂ adsorption and sensing on Janus B₂SeTe: unveiling its electronic, optical, and magnetic properties through DFT and COMSOL†

 Manik Bala, Md Tawabur Rahman, * Raiyan Al Nahean and Md Sakib Hasan Khan 

In this study, the electronic, optical, and magnetic characteristics of a two-dimensional Janus B₂SeTe monolayer, along with its potential for gas sensing applications, were examined using DFT and COMSOL simulations. The interaction and sensing capabilities of various gas molecules, including CO, CO₂, NH₃, SO₂, H₂S, HCN, CH₄, and NO₂, on the B₂SeTe surface were systematically analyzed. Upon geometric optimization, a substantial enhancement in conductivity was observed, increasing by factors of 3.44×10^{13} and 2.44×10^7 upon NO₂ and SO₂ adsorption, respectively. The pristine B₂SeTe monolayer demonstrated remarkable sensitivity and selectivity toward NO₂ and SO₂, with NO₂ showing a notably longer recovery time of 7.2798×10^{-4} s, indicating strong and stable adsorption. The sensor device exhibited an increased response across a concentration range of 25 ppm to 300 ppm, with higher sensitivity to NO₂ (0.02068 ppm⁻¹) compared to SO₂ (0.00953 ppm⁻¹). Furthermore, B₂SeTe displayed optical sensitivity to NO₂, and the observed spin splitting under NO₂ adsorption revealed its magnetic sensing capability. These findings suggest that the Janus B₂SeTe monolayer holds significant promise for future gas sensing applications and environmental monitoring systems.

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1. Introduction

Carbon monoxide (CO), sulfur dioxide (SO₂), methane (CH₄), ammonia (NH₃), hydrogen sulfide (H₂S), carbon dioxide (CO₂), hydrogen cyanide (HCN), and nitrogen dioxide (NO₂) are examples of anthropogenic noxious gaseous chemicals that represent significant environmental pollution and health hazards.¹ These gases are primarily released by industrial processes, the burning of fossil fuels, waste decomposition, automobile exhausts, and agricultural activities. Many of them can cause neurological, cardiovascular, and pulmonary issues, even at low doses. Moreover, being strong greenhouse gases, CH₄, CO₂, and NO₂ all contribute to global warming.^{2,3} Furthermore, the ever-increasing emissions caused by the exponential growth of industry pose a threat to all forms of life on Earth.⁴ Worldwide, 4.2 million people die early each year as a result of outdoor air pollution, which frequently contains harmful chemicals, according to the World Health Organization (WHO). As a result, there is a need for substantial action to identify and separate these dangerous gases.^{5,6} Thus, accidents, occupational sickness, and environmental damage can be prevented with superior, sensitive, and cost-effective toxic-gas-sensing devices.⁷ In the last 10 years, many very sensitive, low-power 2D (two-dimensional) sensors

have been developed.⁸ In addition, the unique mechanical, optical, electrical, and magnetic properties of 2D nanomaterials make them stand out among gas sensor materials.^{9,10} Since the discovery of graphene, the field of 2D nanomaterials has advanced tremendously.¹¹ In the process of materials going from three-dimensional to two-dimensional, numerous scientists have studied a wide range of intriguing physical phenomena.¹² Gas sensing comprises identifying and quantifying specific gases in the environment; 2D materials are well-suited for this task because of their unique properties and huge surface area.¹³ However, graphene's inherent metallic properties reduce the gas sensor's response sensitivity.¹ For superior performance in gas sensors, 2D layered materials with semiconducting properties are required.^{14,15} The transport characteristics of semiconductor 2D layers with tunable electronic properties can be altered by light or gate bias, which makes them very attractive for enhancing sensing capabilities.¹⁶ Transition metal dichalcogenides (TMDs) have excellent properties, such as large band gaps, high carrier mobility, and high surface-to-volume ratios, as well as a hexagonal honeycomb structure, which make them an attractive alternative to graphene.^{6,17}

Recently, TMDs have garnered a lot of interest and are regarded as suitable alternative materials to graphene owing to their fascinating physical and chemical properties, including topological superconductivity, high surface area, abundant active sites, layer-dependent tunable bandgap, chemical stability, indirect-to-direct bandgap crossover, valley-selective optical stimulation, out-of-plane piezoelectric polarization,

Department of Electrical and Electronic Engineering, Khulna University of Engineering & Technology, Khulna-9203, Bangladesh. E-mail: tawabur@eee.kuet.ac.bd

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and a significant Rashba effect because of their out-of-plane asymmetry.^{15,17,18} In particular, the 2D Janus TMDs, such as MoSSe, WSSe, FeClF, MnSSe, PtSSe, In₂SSe, Ga₂SSe, WSTe, HfSeTe, PdSSe, are promising for gas sensing devices.^{19–23} Kumar *et al.*²⁴ utilized a first-principles approach based on density functional theory (DFT) to examine the structural, electronic, and mechanical properties of two-dimensional Janus group III ternary chalcogenide monolayers, including B₂XY, Al₂XY, and BAIX₂, where X and Y represent S, Se, or Te. Among the various Janus TMDs, MoSSe has been successfully synthesized through the chemical vapor deposition (CVD) method.^{25,26} Jin *et al.* reported that Janus MoSSe exhibits significantly enhanced sensitivity to NH₃ and NO₂ gases, attributing this improvement to the built-in electric field and tunable selectivity enabled by its asymmetric Janus structure, making it a promising candidate for ultra-high-sensitivity nanoscale gas sensors.²⁷ Similarly, Kaur *et al.* demonstrated the use of Substituted 2D Janus WSSe monolayers as an efficient nanosensor for CO, NO, and HF gas sensing without imposing external strain.²⁸ More recently, a novel 2D Janus boron selenium telluride monolayer, B₂SeTe, featuring asymmetric Se/Te surfaces, was introduced with superior structural, electronic, photocatalytic, and intrinsic dipole properties.²⁹ Qiu *et al.* investigated the piezoelectric properties of the Janus B₂SeTe monolayer and found that its pronounced out-of-plane piezoelectric response makes it a promising material for applications in top/bottom piezoelectric device technologies.³⁰ However, gas adsorption on B₂SeTe monolayers remains unexplored.

This work investigates the adsorption behaviour and sensing capabilities of various gases on a Janus B₂SeTe monolayer. Using DFT, the study explores the electronic, optical, and magnetic properties of Janus B₂SeTe, including adsorption distances, energies, structural stability, charge transfer, bandgap modulation, electrical conductivity, absorption coefficient, refractive index, and magnetic moment in the presence of different gas molecules. Additionally, NO₂ and SO₂ gas sensors based on Janus B₂SeTe were designed and simulated using COMSOL Multiphysics, incorporating an interdigitated electrode (IDE) configuration. The simulation results demonstrate the high sensitivity and selectivity of the sensors toward NO₂ and SO₂ compared to other gases. These findings highlight the potential of Janus B₂SeTe as a promising material for advanced gas sensing applications.

2. Methodology

2.1 Computational methods based on DFT

First-principles calculations based on DFT were used to compute the electrical and structural relaxations using the CASTEP tool.³¹ To understand the interplay of exchange correlations, the generalized gradient approximation (GGA) with the Perdew–Burke–Ernzerhof (PBE) functional and GGA-PBE + SOC were employed.¹⁰ At Grimme's suggestion, the DFT-D3 approach was used to characterize the van der Waals interaction between the gas molecules and the group III dichalcogenide monolayers.³² A 3 × 3 × 1 supercell of the monolayer B₂SeTe was used in the computational model, which included gas molecules adsorbed

on every surface.³³ A kinetic energy threshold of 520 eV was set, and the total energy that converged was required to meet a tolerance of 10^{−6} eV. The electrical characteristics are computed using the 4 × 4 × 1 Monkhorst–Pack *k*-point mesh.³⁴ To determine the optical characteristics and projected density of state (PDOS), the formula 8 × 8 × 1 is utilized. The geometric optimization was carried out using the Broyden–Fletcher–Goldfarb–Shanno (BFGS) algorithm.³⁵ The following variables were initialized: the energy convergence criterion is 1.0 × 10^{−6} eV per atom, the force maximum is 0.01 eV Å, the stress maximum is 0.02 GPa, the displacement maximum is 5.0 × 10^{−4} Å, and the frequency of iterations is 100.³⁶ To ensure optimal performance for both hard compressibility and variable cell parameters, the cell was optimized with a fixed basis quality. The Koelling–Harmon relativistic method was used for computing the electronic properties, whereas the norm-conserving method was employed for pseudopotentials. Using the GGA and GGA + SOC methods, the electronic properties of NO₂ and NH₃ were calculated, revealing that the splitting of energy bands is caused by the interplay of angular momentum and orbital angular momentum.³⁷ The adsorption energy was calculated using eqn (1).²⁵

$$E_{\text{ad}} = E_{(\text{B}_2\text{SeTe}+\text{gas})} - E_{(\text{B}_2\text{SeTe})} - E_{(\text{gas})} \quad (1)$$

The energy of the B₂SeTe monolayer following gas adsorption is denoted by $E_{(\text{B}_2\text{SeTe}+\text{gas})}$, the energy of the B₂SeTe monolayer itself is denoted by $E_{(\text{B}_2\text{SeTe})}$, and the total energy of the sole gas layer is denoted by $E_{(\text{gas})}$. Eqn (2) was used to determine the amount of charge transfer during the adsorption phase, where ρ_{total} , ρ_{m} , and ρ_{gas} represent the total charge density of the adsorbed structure, the charge density of the pristine molecule, and the charge density of the gas molecule, respectively.

$$\Delta\rho = \rho_{(\text{total})} - \rho_{\text{m}} - \rho_{\text{gas}} \quad (2)$$

The charge transfer amount in the adsorption process was calculated using eqn (3):

$$\Delta Q = Q_{\text{ads}} - Q_{\text{iso}} \quad (3)$$

where Q_{iso} and Q_{ads} indicate the total charge of the gas molecule before and after adsorption, respectively. The conductivity from the band gap of a material can be found in the following equation:¹⁰

$$\sigma = A \exp\left(-\frac{E_{\text{g}}}{2k_{\text{B}}T}\right) \quad (4)$$

Here, A is the proportionality constant, E_{g} is the band gap, k_{B} is the Boltzmann constant, and T is the temperature. The relationship between chemiresistive sensitivity and conductivity is defined by eqn (5):¹³

$$\% S\left(\frac{\delta\sigma}{\sigma}\right) = \frac{\exp\left(-\frac{E_{\text{g}}(\text{adsorbed})}{2k_{\text{B}}T}\right) - \exp\left(-\frac{E_{\text{g}}(\text{pristine})}{2k_{\text{B}}T}\right)}{\exp\left(-\frac{E_{\text{g}}(\text{pristine})}{2k_{\text{B}}T}\right)} \times 100 \quad (5)$$



where $E_g(\text{adsorbed})$ represents the band gap after gas adsorption on B_2SeTe , and $E_g(\text{pristine})$ represents the band gap of pristine B_2SeTe . The duration necessary for gas molecules to naturally desorb from the surface of the sensing material is referred to as the recovery period. The recovery duration was determined with the Van't Hoff-Arrhenius equation, as presented below:^{10,38,39}

$$\tau = \nu_0^{-1} \exp\left(-\frac{E_{\text{ad}}}{k_B T}\right) \quad (6)$$

Here, the attempt frequency is denoted as ν_0 . Previous studies have found that 10^{12} s^{-1} is the attempt frequency for SO_2 . For all other gases, the same value can be applied.¹³

Gas molecules were subsequently added to the initial adsorption sites to determine the most stable adsorption site. The five chosen adsorption sites: B (top of B atom), Se (top of Se atom), Te (top of the centre of the hexagon), bridge (top of B-Se bonds), and bridge (top of B-Te bonds), are shown in Fig. 1(a). The bond length and angle of the 2D layered Janus structure of B_2SeTe can be seen in Fig. 1(b). The sandwich structure best describes these structures, which exhibit $P3m1(C_3V)$ symmetry. Within the B_2SeTe monolayer, the unit cell's lattice constants are $a = b = 4.075 \text{ \AA}$. These lattice parameters match the earlier research on this substance. An example of a unit cell in Fig. 1(a) is marked by the red rhombus box. This cell contains a four-atom basis lattice, with one selenium (Se) atom, two metallic boron atoms, and one tellurium (Te) atom. Fig. 1(b), in its side view, shows the Z-axis order of covalently bound atomic layers as Se-B-B-S, suggesting that boron is sandwiched between selenium (Se) and tellurium (Te) atoms.

2.2 Computational methods on COMSOL

The sensor is built on a $1 \times 2 \times 0.1 \text{ mm}^3$ alumina (Al_2O_3) substrate and comprises four main components: the sensing layers, the IDE, the heater, and the substrate itself, as shown in Fig. S1(a).†^{40,41} The B_2SeTe monolayer on top of IDEs acts as a sensing layer, and the bottom electrodes serve as heaters.^{42,43} The thickness of the B_2SeTe layer was set to 0.5 \mu m , with a surface area of $950 \times 1700 \text{ \mu m}^2$ to represent a realistic device-scale geometry. On the rear face of the Al_2O_3 substrate, an $800 \times 500 \text{ \mu m}^2$ patch of RuO_2 acts as a resistive heater, allowing the sensor's temperature to be modulated (including operation at room temperature) by adjusting the bottom-electrode voltage within COMSOL Multiphysics.⁴⁴ The entire assembly sits inside a sealed, cylindrical test chamber (4 mm in diameter and height) equipped with one inlet and two 0.35 mm radius outlets, as shown in Fig. S1(b).† During the gas sensing experiments, the target gas is introduced through the inlet and exits *via* the outlets; flow-induced pressure causes the thin sensor membrane to flex slightly. As the gas travels from the inlet to the outlet, its concentration decreases progressively.^{40,45} Various amounts of gas were injected into the chamber through the inlet and exposed to the sensor surface during the simulation.⁴⁶ The chamber was emptied of any remaining gas before each measurement. The researchers in this work utilized COMSOL Multiphysics to resolve PDEs and the physical interactions that go along with them. With COMSOL Multiphysics, you can access several modules.⁴⁷

The Navier-Stokes equation is employed to describe the gas flow within the chamber.⁴⁸

$$\rho = -\nabla P + \rho g + \eta \nabla U \quad (7)$$

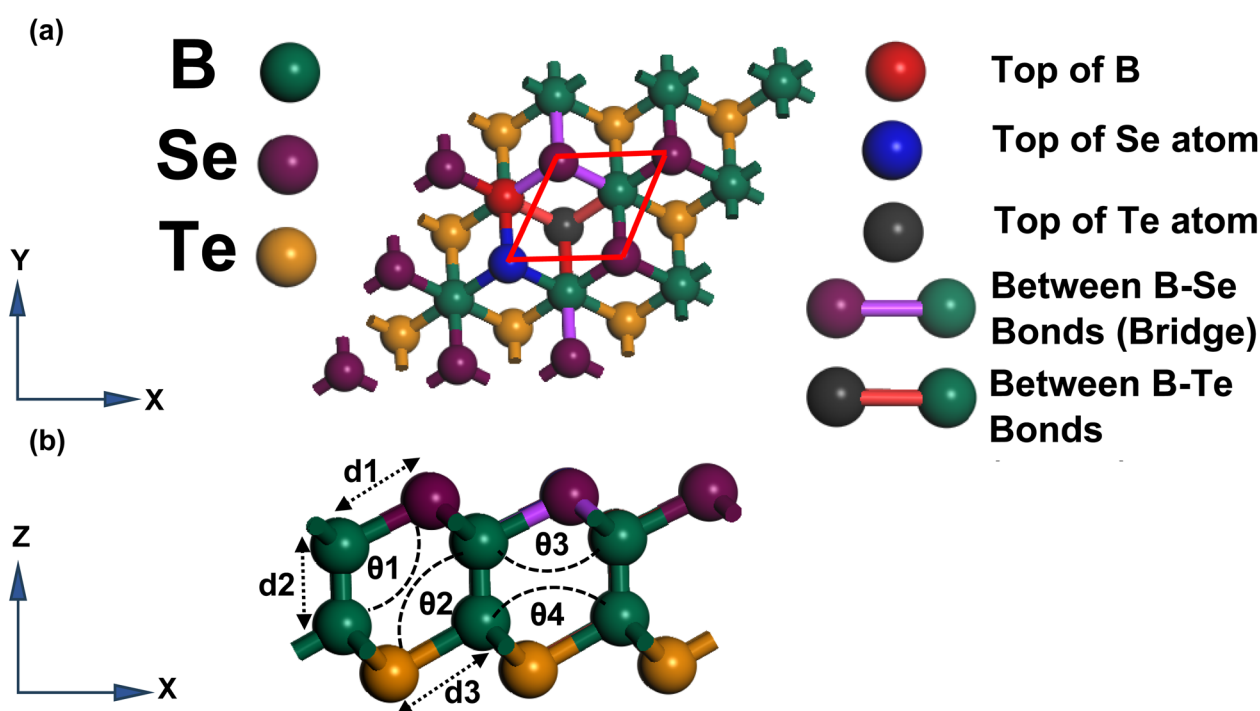


Fig. 1 The optimized structure of the B_2SeTe monolayer showing the (a) five adsorption sites and (b) optimized parameters.



where P , ρ , η , U , and g represent gas pressure, gas flux, viscosity, velocity field, and gravity, respectively. To determine the gas's velocity and field, the Navier–Stokes equations must be solved with the equation of continuity:^{48,49}

$$\rho + \nabla(\rho U) = 0 \quad (8)$$

Given the incompressibility of gas flow, where ρ remains constant, the equation can be written as:

$$\nabla U = 0 \quad (9)$$

$$UT = 0 \quad (10)$$

The gas chamber walls are in a no-relative-motion situation, with UT standing for the peripheral velocity.

According to Fourier's rule, a material's heat transfer rate is proportional to the negative gradient of its temperature.

$$q'' = -kT\nabla \quad (11)$$

Here, T , q'' , and k represent the temperature, flux density, and thermal conductivity, respectively. The conductivity, σ , can be expressed as:

$$\sigma = en\mu \quad (12)$$

Where the charge, carrier concentration, and mobility are represented by e , n , and μ , respectively. The sensor conductivity upon the exposure of a target gas at concentration C can be expressed as:^{50,51}

$$\sigma = (n - \alpha Ct)e\mu \quad (13)$$

where α is the adsorption coefficient, and t represents the per unit surface area of the active layer. This equation can be modified to:

$$\sigma = e\mu(n - \alpha\Delta t) \quad (14)$$

$$\text{Sensor response} = R_a/R_g \quad (15)$$

where R_g and R_a stand for the sensing layer's resistance in the presence of gas and air, respectively.

3. Results and discussion

3.1 The electronic and structural properties of Janus B₂SeTe monolayer

The pristine B₂SeTe Janus structure was first developed and examined for structural stability. Fig. 1 shows that for the pristine B₂SeTe structure, the bond lengths of B–Se (d_1), B–B (d_2), and B–Te (d_3) are 2.153 Å, 1.683 Å, and 2.129 Å, respectively, and the angles of B–B–Se (θ_1), B–B–Te (θ_2), B–Se–B(θ_3) and B–Te–B (θ_4) are 114.329°, 117.871°, 104.215°, and 99.914°, respectively, and the effective thickness of the B₂SeTe structure (t) is 4.9 Å.

Fig. 2 shows the phonon dispersion, electronic band structures, and PDOS of the B₂SeTe monolayer. The phonon dispersion shows no imaginary frequencies, indicating that the structure is dynamically stable (Fig. 2(a)). The phonon band dispersion of the B₂SeTe structure shows a total of 12 phonon branches. Three of these branches are acoustic, while the other nine are optical, consistent with theoretical conclusions.³⁵ Even at the high-symmetry locations close to the zone boundary, the gap in the phonon dispersion separates the degenerate and non-degenerate branches. In addition, the acoustic branches are scattered linearly close to the Gamma point, which is consistent with the typical characteristics of two-dimensional monolayers, matching previous research.²⁴ Fig. 2(b) shows the electrical band structure of the pristine B₂SeTe monolayer. The calculated GGA-PBE bandgap is 2.151 eV, consistent with previous research.^{29,30} The band gap formation occurs between the Γ -high-symmetry point in the valence band maximum (VBM) and the M-high point in the conduction band minimum (CBM). Fig. 2(c) demonstrates that the Se-p and B-p orbitals contribute most to the VBM while the B-p orbital contributes most to the CBM, based on the PDOS. Table S1† integrates all structural property data for the Janus monolayer, including the work function, bandgap value, and associated positions of the VBM and CBM.

3.2 Gas adsorption behaviour on Janus B₂SeTe monolayer

Fig. 3 shows the top view and side view of the most energetically favourable adsorption configurations for (a) NH₃, (b) HCN, (c) CO, (d) NO₂, (e) CH₄, (f) SO₂, (g) H₂S, and (h) CO₂ gas molecules on the B₂SeTe monolayer. Additionally, the orientations of the

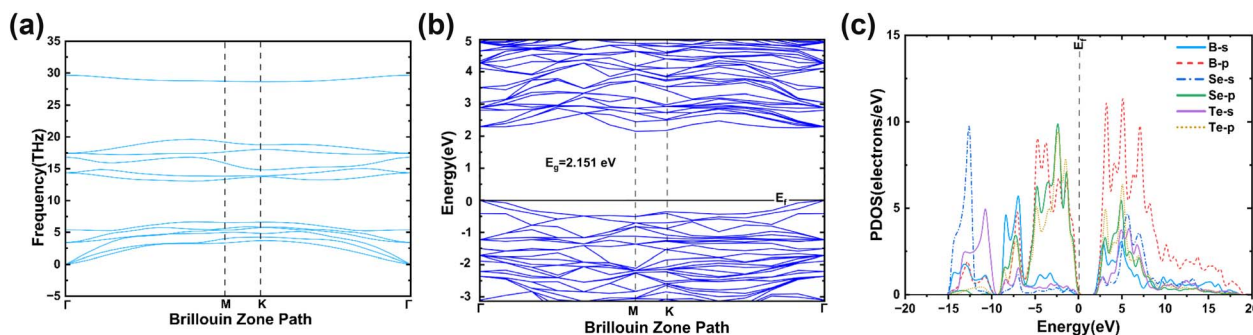


Fig. 2 (a) The phonon dispersion, (b) band structure, and (c) PDOS of the pristine B₂SeTe monolayer with a band gap of 2.151 eV.



gas molecules are also different. The charge transfer and adsorption energy are assessed to determine the adsorption properties. A chemisorption process generally requires an adsorption energy of -0.5 eV or less (higher in absolute value).^{10,35} The subsequent section addresses the adsorption configurations and the characteristics of gas molecule adsorption.

3.2.1 NH₃. The B₂SeTe monolayer showed inefficient NH₃ adsorption with an energy of -0.218 eV. According to Fig. 3(a), the optimal location for adsorption was on top of the Te atom. The adsorption distance between the B₂SeTe monolayer and the NH₃ gas molecule was determined to be 3.11 Å. There was no impact on the conductivity as a chemiresistive gas sensor for NH₃ detection due to the insignificant change in band gap of about 0.002 eV. With a charge transfer of $-0.053e$, charge was transferred from the B₂SeTe monolayer to NH₃, indicating that

NH₃ served a charge acceptor due to the negative sign. As shown by the significant charge depletion on the Se and B atoms in Fig. 4(a), charge was depleted on the H atoms and accumulated on the Se atoms, with a modest buildup on the N atom. Because of the long distance, low adsorption energy, and charge transfer, NH₃ was physisorbed on the B₂SeTe monolayer.

3.2.2 NO₂. The B₂SeTe monolayer's predicted adsorption energy for NO₂ is -0.528 eV, indicating a highly energetically favourable adsorption mechanism. The apex of the B-Se bond was found to be the ideal adsorption location, as shown in Fig. 3(d). With a surface-to-molecule distance of 2.51 Å, the measured adsorption distances for N-Se and N-B bonds were roughly 2.805 Å and 4.078 Å, respectively. Out of all the gas molecules, NO₂ had the shortest adsorption distance. After NO₂ gas adsorption, a notable band gap change of -0.163 eV was produced, suggesting that the B₂SeTe monolayer is extremely

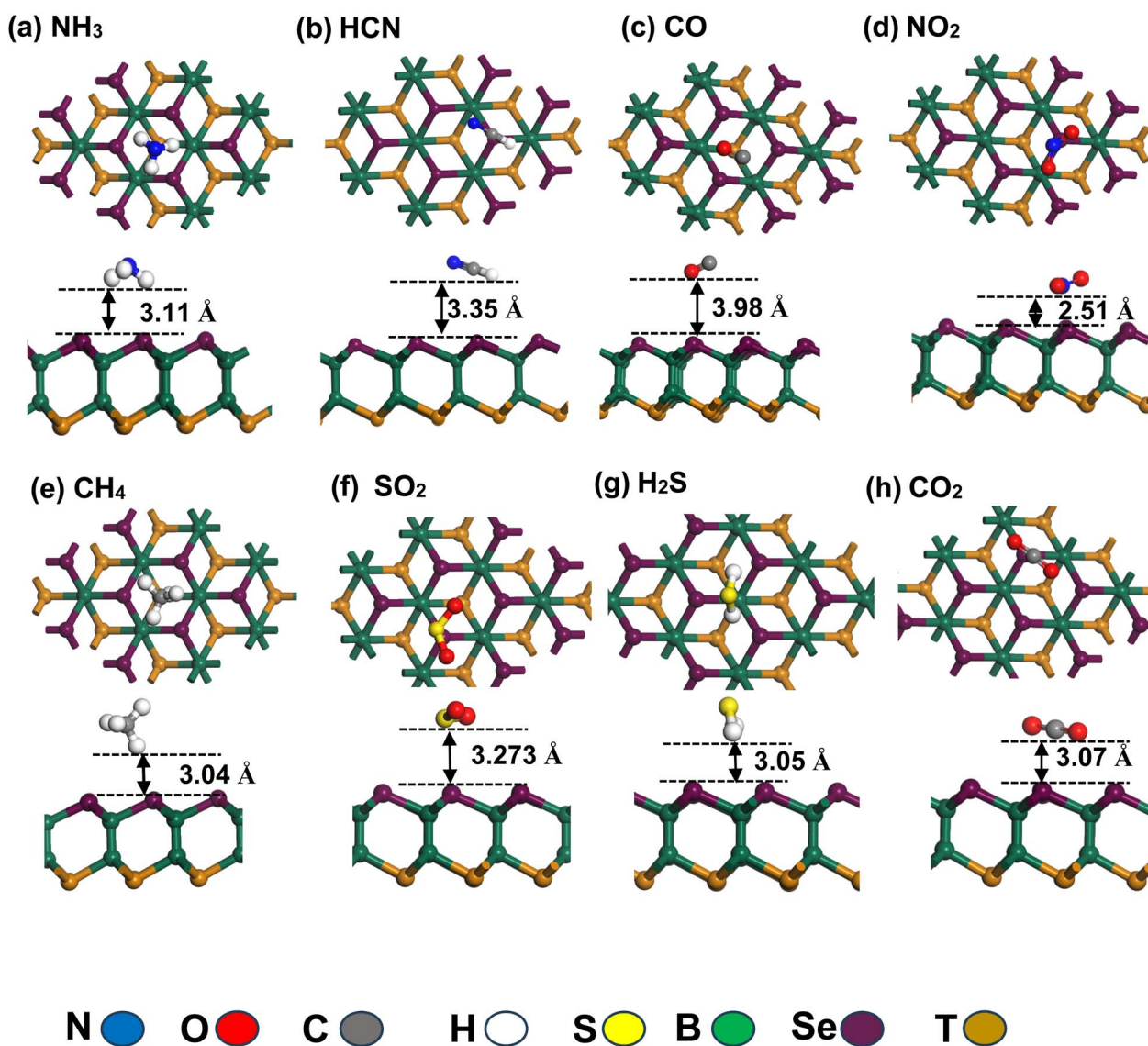


Fig. 3 Top and side view of the most energetically favourable adsorption configuration of (a) NH₃, (b) HCN, (c) CO, (d) NO₂, (e) CH₄, (f) SO₂, (g) H₂S, and (h) CO₂ gas molecules on the B₂SeTe monolayer.



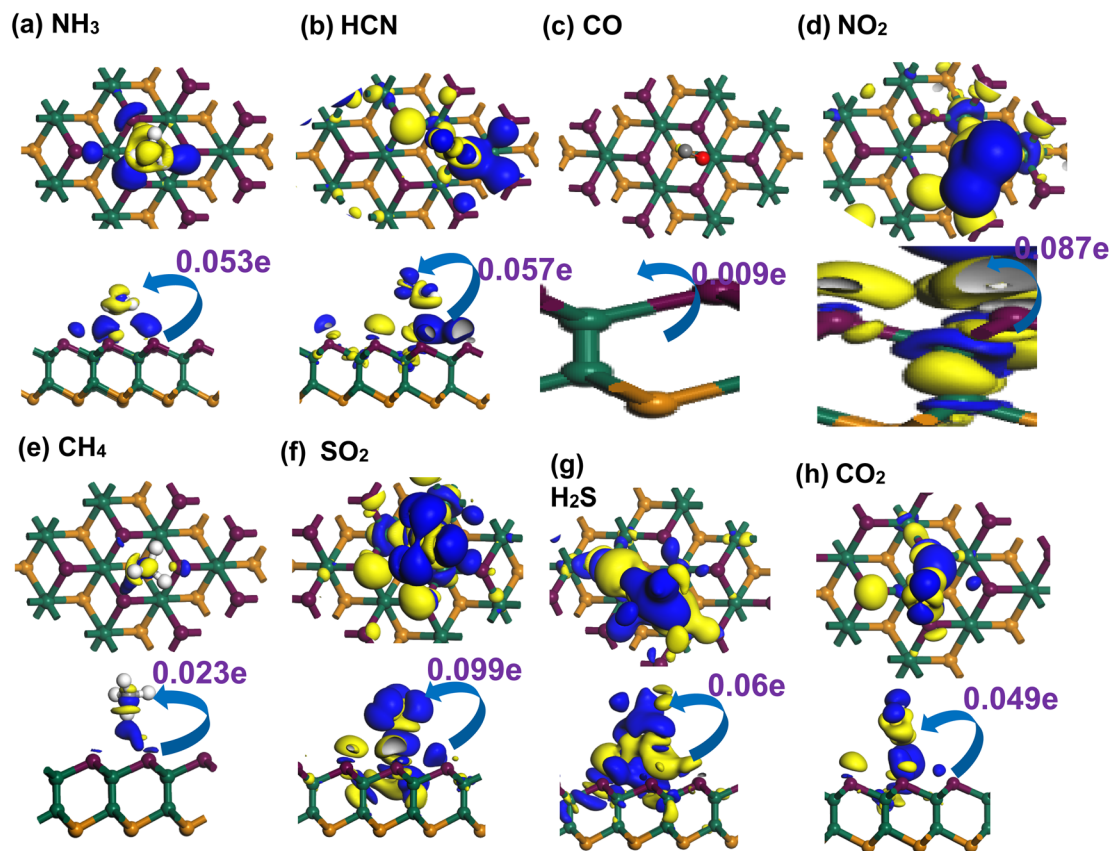


Fig. 4 Charge density difference (CDD) plots for (a) NH_3 , (b) HCN , (c) CO , (d) NO_2 , (e) CH_4 , (f) SO_2 , (g) H_2S , and (h) CO_2 adsorbed on the B_2SeTe monolayer. The blue (yellow) signifies electron accumulation (depletion). The isovalue is 0.001 electrons per unit \AA^3 .

sensitive and selective for NO_2 gas molecules. From the B_2SeTe to the NO_2 gas molecule, the Hirshfeld charge transfer is $-0.087e$. The large charge deposited on the N atom, as seen in Fig. 4(d), and the significant charge depletion on the Se and B atoms further supports the negative sign, which indicates that NO_2 acts as a charge acceptor. The NO_2 molecule appears to be chemisorbed on the B_2SeTe monolayer based on the substantial adsorption energy, low adsorption distance, and charge transfer.

3.2.3 SO_2 . Adsorption of SO_2 onto the B_2SeTe monolayer was found to have an energetically unfavourable adsorption energy of -0.13 eV. Fig. 3(f) shows that the best place for adsorption was at the very top of the B–Se bond. The effective longitudinal adsorption distance was 3.273 \AA , and the distances for S–Se and S–B bonds were around 3.37 \AA and 4.701 \AA , respectively. According to the calculations, the Hirshfeld charge transfer from B_2SeTe to SO_2 gas is $-0.099e$, which was the largest among all gas molecules. The negative sign and the substantial charge depletion on the Se and B atoms and a considerable accumulation on the S atom (Fig. 4(f)) show that SO_2 is a charge acceptor. The substantial charge transfer, low adsorption energy, and medium adsorption distance support the physisorption of SO_2 on the B_2SeTe monolayer.

3.2.4 HCN . The adsorption energy of HCN on the B_2SeTe monolayer is notably low at -0.1 eV. Fig. 3(b) indicates that the

top of the Se atom functioned as the optimal adsorption site, with a total adsorption distance of 3.35 \AA . The B_2SeTe and HCN gas molecules exhibit a Hirshfeld charge transfer of $-0.057e$. A negative sign signifies that HCN acts as a charge acceptor, and Fig. 4(b) illustrates considerable charge depletion in the Se and B atoms. Some charge is also accumulated on the H atoms and Se atoms indicated in blue. The low adsorption energy, considerable adsorption distance, and charge transfer suggest that the HCN gas molecule is physically adsorbed onto the B_2SeTe monolayer.

3.2.5 H_2S . The adsorption energy calculated for H_2S was about -0.1 eV. As shown in Fig. 3(g), the B atom's top surface was the most favourable location for adsorption. The adsorption distance between the upper surface and the gas molecule was 3.05 \AA . The estimated Hirshfeld charge transfer from a B_2SeTe molecule to a H_2S gas molecule is $-0.06e$, which can be identified in Fig. 4(g). There was considerable charge accumulation on S atoms with charge depletion on the Se atoms. However, according to the results in Fig. 5(d), a notable shift of 0.015 eV in the band gap was seen upon H_2S adsorption on the B_2SeTe monolayer. The presence of charge transfer, low adsorption energy, and high adsorption distance suggests that the H_2S molecule is physisorbed onto the B_2SeTe monolayer.

3.2.6 CO_2 . A very weak and steady adsorption of CO_2 was determined to occur on the B_2SeTe monolayer, with an



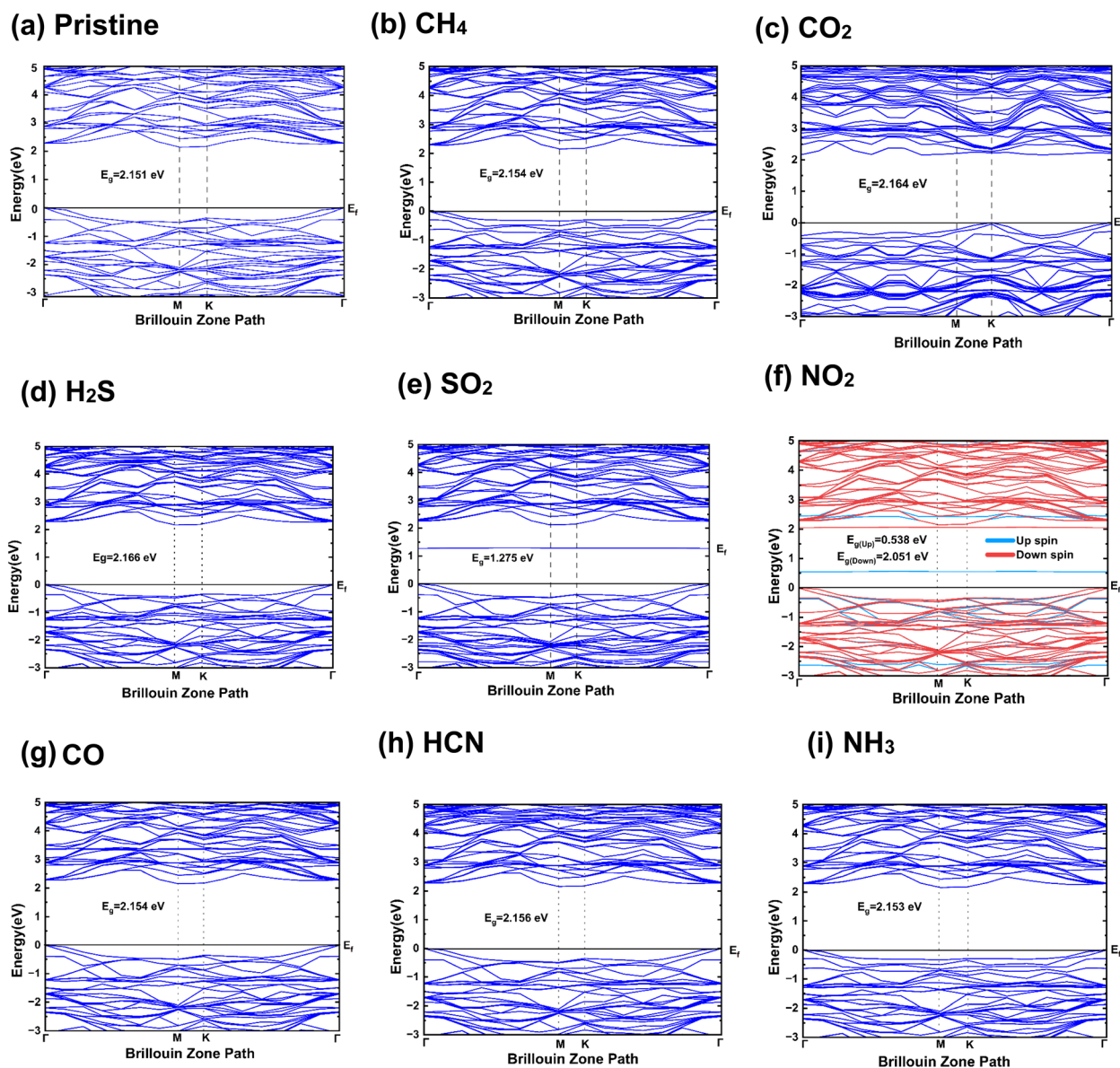


Fig. 5 The band structures of (a) the pristine B_2SeTe monolayer and the B_2SeTe monolayer with (b) CH_4 , (c) CO_2 , (d) H_2S , (e) SO_2 , (f) NO_2 , (g) CO , (h) HCN , and (i) NH_3 adsorbed. The blue (red) color indicates up (down) spin.

adsorption energy of -0.015 eV. As seen in Fig. 3(h), the preferred adsorption site was the top of the B atom. CO_2 adsorbs on the monolayer surface with an effective adsorption distance of 3.07 Å. Between the B_2SeTe and CO_2 gas molecules, the estimated Hirshfeld charge transfer is $-0.049e$. The charge transfer is evident from the charge depletion observed on the B_2SeTe monolayer surface and the charge accumulation on the CO_2 molecule, as illustrated in Fig. 4(h). The negative sign denotes that CO_2 functions as a charge acceptor. The CO_2 molecule appears to be physically adsorbed on the B_2SeTe monolayer, as evidenced by the low adsorption energy, high adsorption distance, and charge transfer.

3.2.7 CO. Adsorption of CO onto the B_2SeTe monolayer was found to have an energy of -0.017 eV, suggesting very weak and

persistent adsorption. As seen in Fig. 3(c), the preferred adsorption site was the top of the Te atom. CO adsorbs with the largest adsorption distance of 3.98 Å on the B_2SeTe monolayer. According to the calculations, the Hirshfeld charge transfer from B_2SeTe to CO gas is $-0.009e$, which was the lowest among all the gas molecules. No charge piling between the CO molecule and the B_2SeTe monolayer was observed, as shown in Fig. 4(c). When CO comes close to the surface, not enough interaction takes place between the CO and the B_2SeTe monolayer. Characteristics such as limited charge transfer, long adsorption distance, and low adsorption energy suggest that the CO molecule is physically adsorbed onto the B_2SeTe monolayer.

3.2.8 CH_4 . The adsorption energy of CH_4 on the B_2SeTe monolayer was -0.002 eV, signifying poor and stable



adsorption. Fig. 3(e) illustrates that the higher Se atom was the favoured adsorption site, with the adsorption distance measured at 3.04 Å. Nevertheless, upon the adsorption of CH₄ onto the B₂SeTe monolayer, the band gap exhibited a notable alteration of 0.003 eV, as illustrated in Fig. 5(b). The predicted Hirshfeld transfer involves transferring $-0.023e$ of charge from B₂SeTe to CH₄ gas. The charge transfer is manifested in the charge depletion noted on the B₂SeTe monolayer surface and the charge accumulation on the CH₄ molecule, as depicted in Fig. 4(e). The charge is predominantly concentrated on the carbon atom and the lower hydrogen atom. The low adsorption energy, significant adsorption distance, and charge transfer indicate that CH₄ is physisorbed on the B₂SeTe monolayer.

3.3 Electronic structures and atomic contributions after gas adsorption

The presence of gas molecules is anticipated to modify the electronic structures of the B₂SeTe monolayer. Consequently, the orbital PDOSs and band structures were computed. Fig. 5 shows the band structures of all gas-adsorbed systems. Fig. 5(b)

and (i) demonstrates that the impact of CH₄ and NH₃ on the electronic properties of the B₂SeTe monolayer is negligible. The observed change in the band gap was insignificant. The nitrogen and hydrogen atoms in NH₃ and CH₄ molecules contribute negligibly to the DOS, as depicted in Fig. 6(b) and (i). B-p and Se-p orbitals contribute most to the conduction band (CB) and valence band (VB), respectively, the same as for the pristine B₂SeTe. The adsorption of SO₂ altered the electronic structure of the B₂SeTe monolayer, leading to a decreased band gap of 1.295 eV, as depicted in Fig. 5(e). A significant hybridization among the p orbitals of Se, O, and S atoms was observed in the CB in the range of 1 eV to 2 eV, as shown in Fig. 6(e). This hybridization may have caused a shift in the CB, perhaps altering the band gap. A new state occurs, mainly due to the contribution of O-p orbitals both in CB and VB. The substantial hybridization also occurred when NO₂ was adsorbed onto B₂SeTe. In this case, hybridization occurred between the p orbitals of nitrogen and selenium atoms. The adsorption of NO₂ led to the formation of new states, as depicted in Fig. 6(f). Incorporating extra states within the 0.5 to 1.5 eV range led to a notable decrease in the band gap to 0.538 eV following NO₂

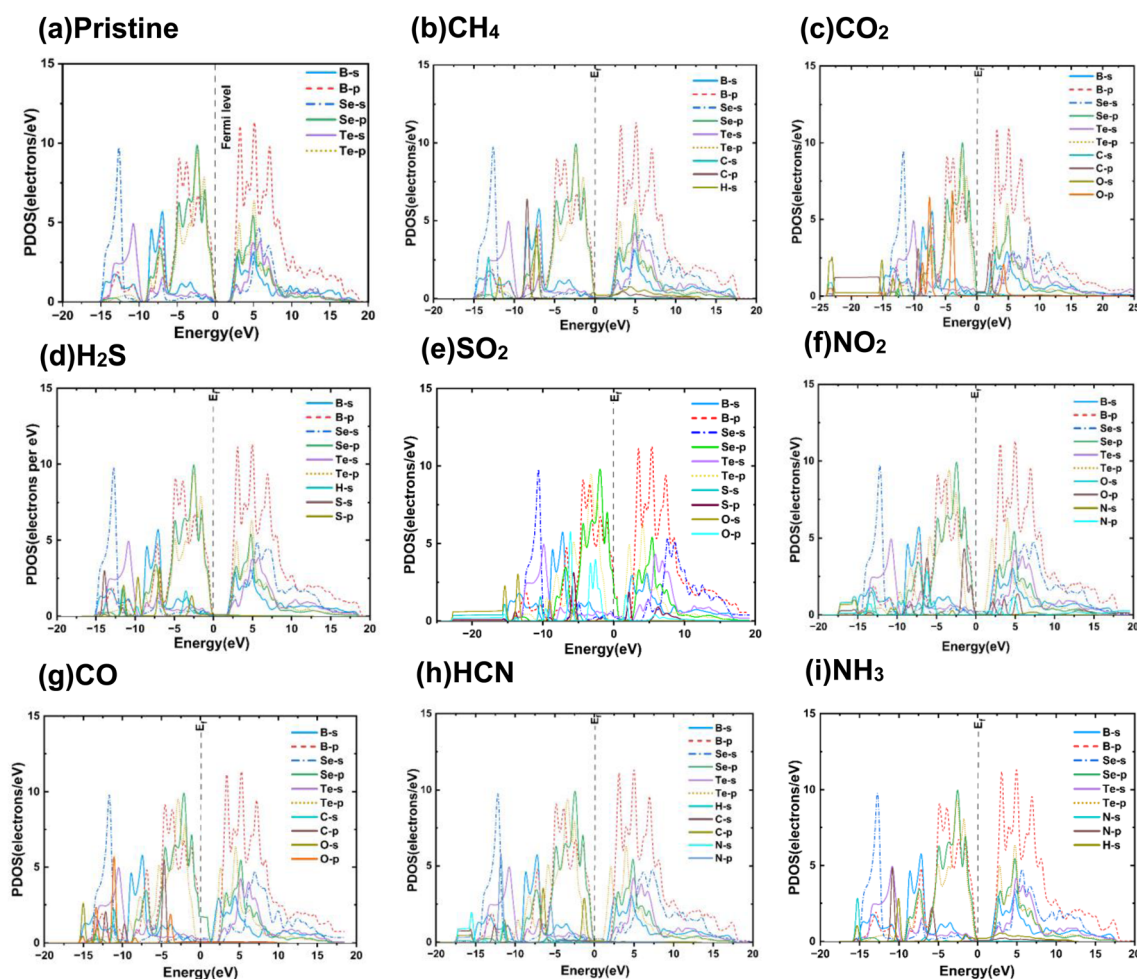


Fig. 6 The orbital projected density of states of (a) the pristine B₂SeTe monolayer and B₂SeTe monolayer with (b) CH₄, (c) CO₂, (d) H₂S, (e) SO₂, (f) NO₂, (g) CO, (h) HCN, and (i) NH₃ adsorbed. NO₂ adsorption substantially decreases the band gap to 0.538 eV, while other gas-adsorbed structures have a band gap reasonably similar to the pristine band gap of 2.151 eV.



adsorption, as depicted in Fig. 5(f). Furthermore, substantial hybridization between the orbitals of NO₂ and B₂SeTe was observed. Fig. 6(f) demonstrates that the p orbitals of N atom hybridize with the s and p orbitals of boron and selenium in the 0.5 to 2 eV range. The p orbitals of O atoms hybridize with the p orbitals of Se atoms, exhibiting energy levels between -0.5 and -1.5 eV in the VB. The changes in the band gap were primarily caused by the O-p orbitals. Additionally, a large band gap change leads to a change in conductivity. A significant amount of variation in the conductivity of the B₂SeTe monolayer is responsible for the sensitivity of the material. This makes it suitable for application as a chemiresistive gas sensor. In contrast, H₂S adsorption did not alter the electronic structure of the B₂SeTe monolayer. However, weak hybridization between the sulfur and boron atoms is observed in the 2 to 4 eV range within the VB, as depicted in Fig. 6(d). The change in the band gap was negligible (0.09 eV), as depicted in Fig. 5(d). The HCN adsorption modified the electronic structure of the B₂SeTe monolayer. Fig. 6(h) demonstrates that the p orbitals of the carbon atom in the HCN molecule undergo substantial hybridization with the p orbitals of the boron atom throughout the 1.8 eV to 2.2 eV range of the CB. S-p orbitals contribute most near the Fermi level in the VB and B-p orbitals in the CB, as in the pristine structure. The adsorption of HCN resulted in a variation of 0.097 eV, as depicted in Fig. 5(h). The adsorption of CO₂ and CO had a negligible impact on the electronic structure of the B₂SeTe monolayer, leading to minimal alterations in the band gap of merely 0.013 eV and 0.003 eV, respectively, as depicted in Fig. 5(c) and (g). The contributions of carbon and oxygen atoms in CO or CO₂ molecules to the density of states are minimal, as demonstrated in Fig. 6(c) and (g). Owing to these insufficient contributions, the conductivity of the material did not change after CO₂ and CO gas adsorption, nor did the sensitivity. In the PDOS, developing a novel state is linked to modifying the band gap. A significant fluctuation in the band gap will result in the introduction of a new state inside the PDOS. Thus, the change in conductivity of B₂SeTe could be used for selective gas detection. Table 1 summarizes the adsorption energy (E_{ad}), bandgap (E_g), bandgap change (ΔE_g), adsorption distance (D), Hirshfeld charge transfer (ΔQ), and charge carrier types of the most energetically favourable adsorbed gas structures. From Table 1 and it can be clearly seen that among all the gas molecules, NO₂ is adsorbed with the maximum adsorption energy, shortest adsorption distance, and largest band gap change. A

distinguishing feature can also be noticed for SO₂ due to having the second-highest adsorption energy. The other gases did not exhibit any such unique properties. Table 1 shows the selective nature of B₂SeTe toward NO₂ (SO₂).

Table 2 presents a detailed evaluation of B₂SeTe alongside eight representative 2D materials, comparing key performance metrics such as sensitivity, recovery time, adsorption energy, and charge transfer. The results showed that the B₂SeTe sensor exhibits sensitivity of $3.4401 \times 10^{15}\%$ for NO₂ and $2.2466 \times 10^9\%$ for SO₂, which is significantly higher than that of typical materials such as GaAs, In₂SSe, Ga₂SSe, MoS₂, NbSeTe, and Janus material-based sensors under similar conditions. The charge transfer and adsorption energy revealed a significant interaction between NO₂ and SO₂ gases and the gas sensing B₂SeTe monolayer, especially when compared to other gas sensors. Furthermore, pristine B₂SeTe monolayer demonstrated remarkable sensitivity and selectivity toward NO₂ and SO₂, with NO₂ showing a notably longer recovery time of 7.2798×10^{-4} s, indicating strong and stable adsorption. The recovery time of B₂SeTe remains within a practically acceptable range, supporting its applicability in real-time sensing scenarios. For instance, in the case of GaAs, the sensing of NO₂ gas is unfeasible due to an excessively long recovery time (4.45×10^{12} s), which prevents the sensor from being reused after gas adsorption, and the SO₂ gas detection by NbSeTe was also very difficult as SO₂ molecules will be reabsorbed from the NbSeTe monolayer before detection due to having a recovery time in the picosecond range (251.9×10^{-12} s), which makes these gases unsuitable for sensing. This comparative analysis underscores the superior sensing capabilities of B₂SeTe, particularly for NO₂ and SO₂ detection, and reinforces its potential as a promising next-generation 2D gas sensing material.

3.4 Gas sensing properties of B₂SeTe monolayer: DFT and COMSOL study

A gas sensor is considered highly selective for a particular gas when it only reacts to specific gas molecules and does not react to other gas molecules that are also present. An experiment was conducted to assess how selective the B₂SeTe gas sensor is when it comes to detecting NO₂ gas. Fig. S2† displays the adsorption configurations for different combinations of gases on B₂SeTe. The electronic bandgap only changes in the presence of NO₂ gas mixed with other gases such as CO₂, CO, NH₃, CH₄, H₂S, and HCN, as depicted in Fig. S3(a–d).† However, in the absence of

Table 1 Adsorption energy (E_{ad}), bandgap (E_g), bandgap change (ΔE_g), adsorption distance (D), and Hirshfeld charge transfer (ΔQ) of the most energetically favourable gas adsorption structures

Gas molecules	NH ₃	HCN	CO	NO ₂	SO ₂	CO ₂	H ₂ S	CH ₄
Suitable sites	Top of Te	Top of Se	Top of Te	Between B–Se bond	Between B–Se bond	Top of Se	Top of B	Top of Se
Adsorption distance D (Å)	3.11	3.35	3.98	2.51	3.173	3.08	3.05	3.04
Bandgap (E_g)	2.153	2.156	2.154	0.538	1.275	2.164	2.166	2.154
Change in bandgap (ΔE_g)	0.002	0.005	0.003	-1.613	-0.876	0.013	0.015	0.003
Adsorption energy (E_{ad})	-0.218	-0.1	-0.017	-0.528	-0.13	-0.015	-0.01	-0.002
Charge transfer (ΔQ)	-0.053	-0.057	-0.009	-0.087	-0.099	-0.49	-0.06	-0.023
Charge carrier type	Acceptor	Acceptor	Acceptor	Acceptor	Acceptor	Acceptor	Acceptor	Acceptor



Table 2 Comparison of the sensitivity, recovery time, adsorption energy, and charge transfer of the Janus B₂SeTe monolayer with other traditional gas sensors for detecting NO₂ and SO₂

Materials	Sensitivity (%)		Recovery time		Adsorption energy (eV)		Charge transfer (e)	
	NO ₂	SO ₂	NO ₂	SO ₂	NO ₂	SO ₂	NO ₂	SO ₂
B ₂ SeTe	3.4401×10^{15}	2.2466×10^9	7.2798×10^{-4}	1.5204×10^{-10}	-0.528	-0.13	-0.087	-0.099
GaAs ³³	99	99	4.45×10^{12}	15.93	-1.48	-0.81	0.280	-0.26
In ₂ SSe ³⁵	3.48×10^3	21	9.62×10^{-8}	2.5×10^{-6}	-0.118	-0.202	-0.665	-0.66
Ga ₂ SSe ³⁵	1.13×10^{11}	2.018×10^3	6.41×10^{-7}	1.65×10^{-5}	-0.167	-0.251	-1.05	-0.989
MoS ₂ (ref. 52)	20	7.4	4.32×10^4	56	NA	NA	NA	NA
NbSeTe ⁵³	45	94	75.74×10^{-6}	251.9×10^{-12}	-0.59	-0.26	-0.16	-0.284
Pt-doped HfSSe ⁵⁴	NA	70.1	NA	2.23×10^3	NA	-0.908	NA	-0.069
MoSSe ²⁵	98	89	2.22×10^2	1.30	-0.854	-0.623	0.034	0.056
WSSe ⁵⁵	NA	NA	4.3×10^{-2}	NA	-0.276	NA	-0.057	NA

NO₂, the band gap did not alter significantly. As shown in Fig. S3(d–f),† various gas combinations without NO₂ were tested, but the band gap did not change noticeably, which confirms the selective nature of B₂SeTe toward NO₂. As shown in Fig. S2(g),† a gas combination including SO₂ was tested, and a moderate bandgap change of -0.551 eV was generated, which also depicts the selective nature toward SO₂. Fig. S4† displays the PDOS for the gas mixture in a state diagram. The PDOS diagram in Fig. S4(a–d)† shows that when only NO₂ gas is present, the bandgap becomes very low compared to the pristine value due to a new state being generated in each case in the 0.5 eV to 1.5 eV region. Incorporating extra states within the 0.5 to 1.5 eV range led to a notable decrease in the band gap following gas adsorption, which includes NO₂. Furthermore, substantial hybridization between the orbitals of NO₂ and B₂SeTe was observed. Fig. S4(a–d)† demonstrates that the s and p orbitals of N and O atoms hybridize with the s and p orbitals of boron and selenium in the 0.5 to 2 eV range. Table S II† represents the different gas combinations for detecting the highly selective nature of B₂SeTe, the band gap and band gap change, and the reasons behind this for different gas combinations. It can be seen that the band gap changes are -1.518 eV, -1.468 eV, -1.519 eV, and -1.459 eV for NO₂-containing gas mixtures of (NO₂ + CO₂), (NO₂ + CO), (NO₂ + CO₂ + NH₃), and (NO₂ + CO + CH₄), respectively. This is because of the magnetic (spin-unrestricted) nature of NO₂. Additionally, the band gap changes negligibly to 0.002 eV, 0.009 eV, -0.005 eV, and -0.001 eV for (CO₂ + HCN + H₂S), (H₂S + HCN + NH₃), (CO + CH₄ + NH₃), (NH₃ + CO + CH₄ + H₂S), respectively, owing to the non-magnetic (spin-restricted) nature of the gas mixtures without NO₂.¹² Thus, B₂SeTe is highly selective for NO₂ in the presence of other gases.

The conductivity can be calculated from the band gap using eqn (4), and thus, the sensitivity was calculated from eqn (5). The calculated sensitivity of B₂SeTe monolayer for different gas molecules is shown in Table S II.† The Janus 2D B₂SeTe monolayer demonstrated the most significant bandgap shift of -1.613 and -0.876 eV under the adsorption of NO₂ and SO₂. Owing to the substantial band gap shift, the chemiresistive sensitivity for NO₂ was highest with a value of $3.4401 \times 10^{15}\%$ (Table S II†), while it was $2.2466 \times 10^9\%$ for SO₂. The histogram plot for

change in bandgap and logarithmic sensitivity is shown in Fig. 7(a) and (b). The NO₂-containing gas mixtures produce a significant band gap shift. Consequently, the B₂SeTe monolayer shows enhanced logarithmic sensitivity to NO₂ and NO₂-containing gases in the range of 13.53–14.74. However, a negligible band gap shift as well as low sensitivity were observed for gases other than NO₂-containing gases. Additionally, the B₂SeTe monolayer shows a logarithmic sensitivity of 7.35% toward SO₂, which also points to the highly sensitive and selective nature of B₂SeTe toward SO₂. Therefore, the buckled B₂SeTe monolayer can be utilized as a chemiresistive gas sensor for selective detection of NO₂ and SO₂ gases against a variety of interfering gases.

To guarantee a sensing material's structural integrity under working conditions, it is essential to evaluate its dynamic stability after gas adsorption. In order to achieve this, we determined the phonon dispersion relations following the adsorption of SO₂ and NO₂, which were found to have the most selective and sensitive interactions. Both gas-adsorbed structures are free of imaginary (negative) phonon frequencies, as shown in Fig. S5,† indicating that they maintain their dynamic stability after adsorption. The total lack of soft modes across the Brillouin zone suggests that the adsorbates do not cause any phase transitions or lattice instabilities. Additionally, the distinct separation of the acoustic and optical branches shows that vibrational energy does not localize at the adsorption sites, maintaining the material's inherent mechanical and thermal durability. The sensor's dependable gas sensing capability is supported by its verified dynamic stability, which ensures consistent surface contacts and repeatable electronic responses.

The dynamic response characteristics (*i.e.*, sensor response as a function of time) cannot be effectively analyzed using DFT. However, COMSOL Multiphysics allows for the simulation of the sensor response (R_a/R_g) under specific gas concentrations. Using this platform, it is possible to model the time-dependent behaviour of the sensor for various gas exposures. Fig. 7(c) represents the dynamic characteristics of the developed sensor to 100 ppm of NO₂ and SO₂ with a response of 8.96 and 7.13, indicating effective detection of these gases. The B₂SeTe sensor showed an increasing response toward NO₂ and SO₂ in the range of 25 ppm to 300 ppm (Fig. 7(d)). In particular, both sensors exhibited a linear response in the range of 25 ppm to



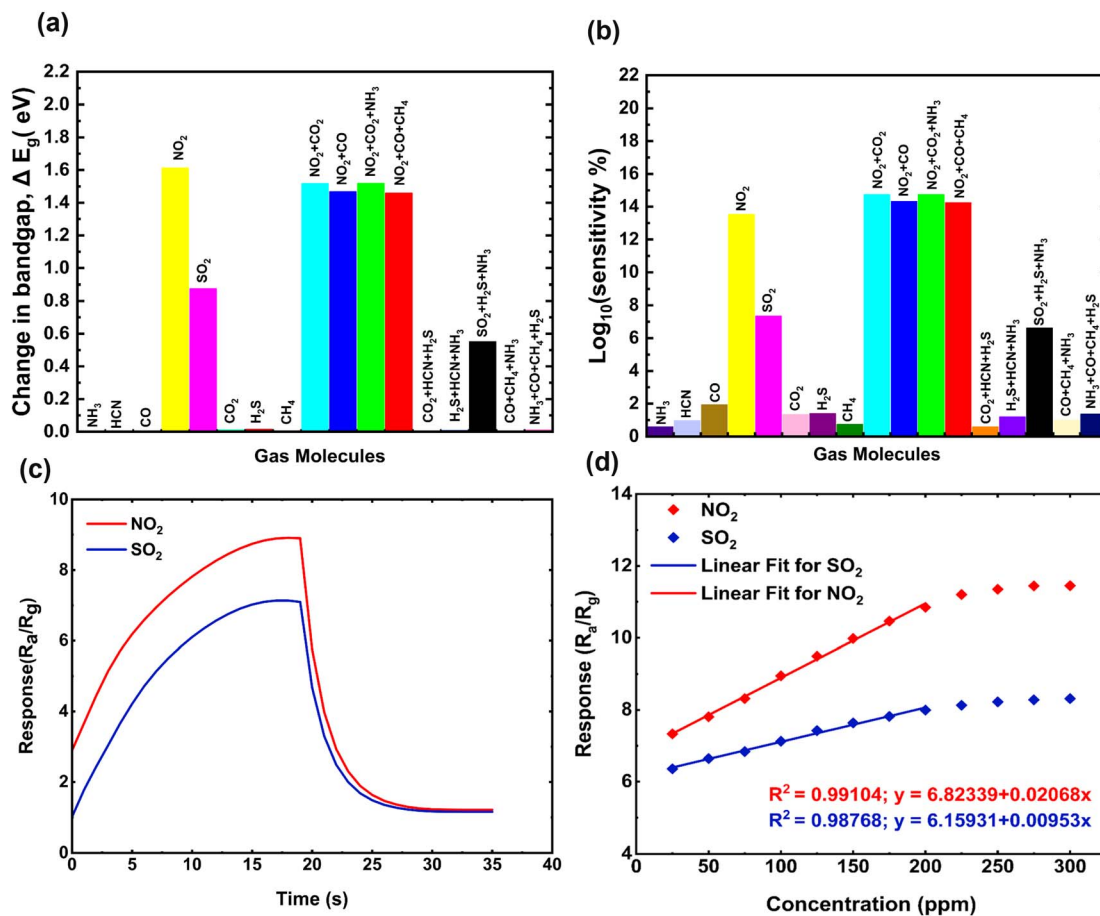


Fig. 7 (a) Change in bandgap (ΔE_g) and (b) bandgap-based logarithmic sensitivity for different gases after adsorption on the B₂SeTe monolayer (c) the dynamic response characteristics of the B₂SeTe sensor under exposure to 100 ppm NO₂ and SO₂ (d) the linear fit of the response vs. concentration curve for the sensor when exposed to NO₂ and SO₂.

200 ppm. The linear correlation between response vs. concentration is described by the equations $y = 6.82339 + 0.02068x$, and $y = 6.15931 + 0.00953x$ for NO₂ and SO₂, where x is the target gas concentration and y is the response. Consequently, the sensor detected NO₂ (0.02068 ppm⁻¹) with greater sensitivity than SO₂ (0.00953 ppm⁻¹). Hence, the exceptional sensitivity and selectivity of the B₂SeTe Janus material toward NO₂ (SO₂) may open new applications for these materials in detecting other hazardous gases.

The recovery time at temperatures between 300 K and 600 K is provided in Table 3, with 300 K serving as the room temperature for the computations. A longer recovery time is always desired for practical gas sensing applications. Table 3 shows the recovery time for different gases between 300 K and 600 K. The recovery time rapidly decreases with increasing temperatures. A longer recovery of 7.2798×10^{-4} s was observed for NO₂ at 300 K, which is suitable for room temperature detection due to sufficient interaction between the NO₂ and B₂SeTe. In contrast, the recovery time for other gases lies in the picosecond range. Therefore, these gases will be reabsorbed from the B₂SeTe monolayer before detection, which makes these gases unsuitable for sensing. A longer recovery time provides accurate sensing performance. Furthermore, at 600 K,

the recovery time increases tremendously for all the gases. Practically, sensing is impossible at high temperatures. Therefore, B₂SeTe is suitable for room temperature detection of NO₂. Although the recovery time of SO₂ lies in the nanosecond region, SO₂ can be detected with less selectivity and accuracy than NO₂.

3.5 Optical and magnetic properties of B₂SeTe monolayer for gas sensing

The optical properties of B₂SeTe monolayer, including the absorption coefficient (AC) and refractive index, were investigated for various gas sensing applications and are shown in Fig. 8. The adsorption coefficient for B₂SeTe increased for the adsorption of CO₂ and H₂S gases, and decreased for other gases, as shown in Fig. 8(a). The magnified image in Fig. 8(a) shows that the peak values of the absorption coefficients shifted under different gases. It is possible to determine the presence of gases such as NO₂ and H₂S by watching the degree to which the absorption peak shifts. It can be seen that the adsorption peak has a redshift of 13 nm and 9 nm for NO₂ and H₂S, respectively. Furthermore, the redshift of the AC peak for all other gases was negligible. Thus, the optical absorption



Table 3 Recovery times for different gases between 300 K and 600 K

Gas molecule	Recovery time (s) at 300 K	Recovery time (s) at 400 K	Recovery time (s) at 500 K	Recovery time (s) at 600 K
NH ₃	4.5601×10^{-9}	5.5492×10^{-10}	1.5681×10^{-10}	6.7529×10^{-11}
HCN	4.7690×10^{-11}	1.8147×10^{-11}	1.0163×10^{-11}	6.9058×10^{-12}
CO	1.9301×10^{-12}	1.6415×10^{-12}	1.4832×10^{-12}	1.3888×10^{-12}
NO ₂	7.2798×10^{-4}	4.4319×10^{-6}	2.0762×10^{-7}	2.6981×10^{-8}
CO ₂	1.7855×10^{-12}	1.5446×10^{-12}	1.4159×10^{-12}	1.3362×10^{-12}
SO ₂	1.5204×10^{-10}	4.3298×10^{-11}	2.0378×10^{-11}	1.23305×10^{-11}
H ₂ S	1.4717×10^{-12}	1.3362×10^{-12}	1.2609×10^{-12}	1.2131×10^{-12}
CH ₄	1.0803×10^{-12}	1.0596×10^{-12}	1.0474×10^{-12}	1.0394×10^{-12}

behaviour of B₂SeTe monolayer can distinguish NO₂ and H₂S among different gases. When considering B₂SeTe, it is observed that the absorption coefficient (AC) of the H₂S(CO₂)-adsorbed structure exhibits a noteworthy increase of 0.51×10^4 (0.812×10^4) cm⁻¹. Additionally, except for CO₂ and H₂S, the AC value decreases for all the gases. With a visible-spectrum refractive index ($\eta = 2.4$ – 2.6), pristine B₂SeTe is an exceptional material for high refractive index polymer (HRIP) and optoelectronic research, as shown in Fig. 8(b), which depicts its numerical value. A discernible improvement of 0.5 and 0.6 results after the adsorption of H₂S and CO₂ on the B₂SeTe monolayer, respectively. Based on the data presented

here, it appears that the B₂SeTe monolayer can perform the functions of a gas sensor that is selective and sensitive in the visible range.

In recent years, there has been a rise in the use of magnetic gas sensors because of their safety and the absence of electrical connections.¹³ Here, adsorption of the NO₂ molecule on the B₂SeTe monolayer was found to induce a magnetic moment. Under NO₂ adsorption, the separation of up-spin and down-spin conduction bands in the band structure of B₂SeTe was observed (Fig. 5(f)), revealing the magnetization of B₂SeTe. In contrast, B₂SeTe is non-magnetic for other gases. However, the induced magnetism for NO₂ adsorption was substantiated by

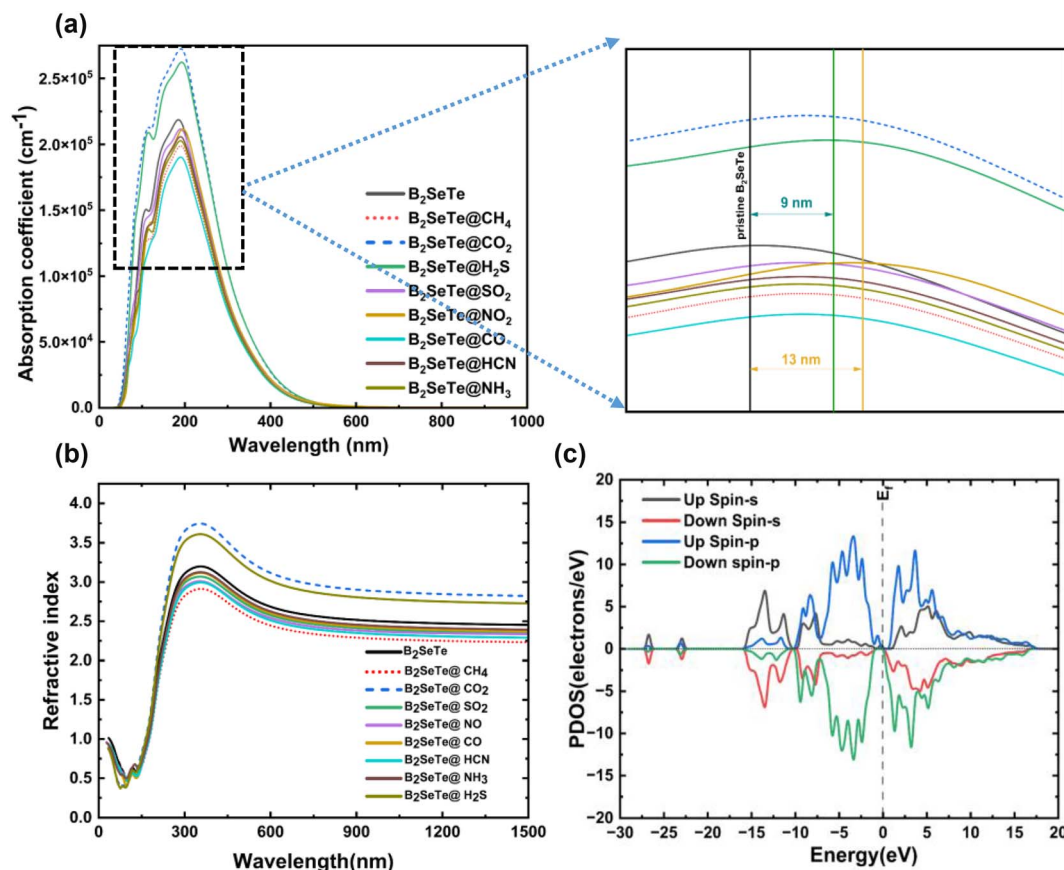


Fig. 8 (a) Adsorption coefficient and (b) refractive index of various gases adsorbed on B₂SeTe; and (c) spin-resolved density of states in the B₂SeTe monolayer with NO₂ adsorbed. The colors red, blue, green, and black stand for the p orbital's up-spin, the s orbital's up-spin, and the s orbital's down-spin, respectively.



the asymmetry in the up-spin and down-spin density of states shown in Fig. 8(c). Therefore, B₂SeTe monolayer could be useful as a magnetic gas sensor to selectively detect NO₂.

4. Conclusions

In conclusion, the electronic, optical, and magnetic properties of the two-dimensional Janus B₂SeTe monolayer were thoroughly investigated and leveraged for the detection of various gas molecules, demonstrating high sensitivity and selectivity. DFT was employed to optimize the geometry and analyze key parameters such as band structure, bandgap energy, adsorption distance, charge transfer, lattice constants, PDOS, and CDD for the adsorption of NH₃, NO₂, SO₂, CO₂, H₂S, CO, HCN, and CH₄ on the B₂SeTe surface—confirming its viability as a gas sensing material. The phonon dispersion analysis confirmed that B₂SeTe exhibits all positive frequencies, indicating dynamic stability suitable for gas adsorption. Among the studied gases, only NO₂ was found to chemisorb onto the surface, while the others exhibited physisorption behaviour. NO₂ showed the highest adsorption energy and the shortest adsorption distance, signifying a strong interaction with the monolayer. The adsorption of NO₂ and SO₂ caused significant bandgap reductions to 1.613 eV and 0.876 eV, respectively, from the pristine value of 2.151 eV. These changes correspond to conductivity enhancements by factors of approximately 3.44×10^{13} (NO₂) and 2.44×10^7 (SO₂). The charge transfer analysis indicated that NO₂ and SO₂ act as electron acceptors, with transferred charge densities of $0.087 \text{ e } \text{\AA}^{-3}$ and $0.099 \text{ e } \text{\AA}^{-3}$, respectively. The COMSOL Multiphysics simulations further confirmed the practical sensing capability, showing that both gases are detectable at concentrations as low as 25 ppm, with sensitivity increasing linearly up to 300 ppm. The sensor exhibited a higher sensitivity to NO₂ (0.02068 ppm⁻¹) compared to SO₂ (0.00953 ppm⁻¹). Additionally, the sensor demonstrated a longer recovery time of $7.2798 \times 10^{-4} \text{ s}$ toward NO₂ at room temperature, suggesting a more stable interaction and efficient detection. The optical sensing capability was also indicated by a redshift in the AC of pristine B₂SeTe by 13 nm and 9 nm upon exposure to NO₂ and H₂S, respectively. Furthermore, magnetic sensing potential was revealed by the spin splitting in the conduction bands under NO₂ adsorption, indicating spin polarization. Overall, the exceptional selectivity, sensitivity, and multifunctional response of Janus B₂SeTe monolayer to NO₂ and SO₂ make it a highly promising candidate for next-generation toxic gas detection technologies.

Data availability

The data supporting this article have been included as part of the ESI.†

Conflicts of interest

All authors declare that they have no conflict of interest.

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